

アキシアルリード形セラミックコンデンサ

AXIAL LEADED CERAMIC CAPACITORS

OPERATING TEMP. -25~+85°C



フロー/WAVE

特長 FEATURES

- 汎用型セラミックコンデンサで、単層形と積層形合わせて1pF~10μFと広い容量範囲で部品の標準化が可能
- ラジアルに比べ自挿コストが安く、部品高さを低減、実装密度アップ、在庫スペースも減少
- 実装ピッチ5mmから26mmまでジャンパー線機能と兼用可能

- This widely used ceramic capacitor includes both monolithic and multi-layer types to provide a wide capacitance range of 1pF through 10μF in one standard size and shape.
- Automatic insertion related costs are lower than with radial type capacitors.
- Mounting pitch can be between 5mm to 26mm which could be used as a jumper.

用途 APPLICATIONS

- Class1品は回路の温度特性補正及び周波数特性の安定化。B、F特はバイパスコンデンサに最適

- The class 1 temperature compensating (NPO) products can be used in circuits to stabilize frequency and temperature characteristics.
- The B, and F dielectrics are optimum for bypass capacitors.

形名表記法 ORDERING CODE

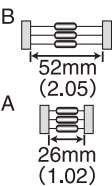
1 定格電圧 [VDC] L 10 E 16 T 25 G 35 U 50	3 形状寸法 (L×φd) [mm] 075 4.2×3.2 (積層形) 050 3.5×1.9 (単層形) 3.2×2.2 (積層形) 025 2.3×2.0 (積層形) 015 3.0×2.5 (積層形)	5 公称静電容量 [pF] 例 ※R=小数点 010 1 1R2 1.2 103 10000	6 容量許容差 D- ±0.5pF J- ±5% K- ±10% M- ±20% Z- ±80/±20%	8 梱包 B つづら折り C 袋づめ
2 形式 P アキシアルリードコンデンサ	4 温度特性 CK 0±250 (ppm/°C) CH 0±60 (ppm/°C) RH -220±60 (ppm/°C) UJ -750±120 (ppm/°C) SL +350~-1000 (ppm/°C) △B ±10% △F ±30/-85% △=スペース	7 リード形状 [mm] A- 26mmテープ幅テーピング B- 52mmテープ幅テーピング KF 5.0mmピッチフォーミング KE 7.5mmピッチフォーミング NA 単品ストレートリード	9 当社管理記号 △△ 単層標準品 △Z 積層標準品 △J 積層品 (低電圧タイプ) △=スペース	

U P 0 5 0 C H 1 0 0 J - A - B ○ ○

1 2 3 4 5 6 7 8 9

1 Rated voltage [VDC] L 10 E 16 T 25 G 35 U 50	3 Outside Dimensions (L×φd) [mm] 075 4.2×3.2 (multilayer type) 050 3.5×1.9 (monolithic type) 3.2×2.2 (multilayer type) 025 2.3×2.0 (multilayer type) 015 3.0×2.5 (multilayer type)	5 Nominal Capacitance [pF] example 010 1 1R2 1.2 103 10000 ※R=decimal point	6 Capacitance Tolerances D- ±0.5pF J- ±5% K- ±10% M- ±20% Z- ±80/±20%	8 Packaging B Ammo C Bulk
2 Type P Axial leaded capacitors	4 Temperature characteristics CK 0±250 (ppm/°C) CH 0±60 (ppm/°C) RH -220±60 (ppm/°C) UJ -750±120 (ppm/°C) SL +350~-1000 (ppm/°C) △B ±10% △F ±30/-85% △=Blank space	7 Lead Configuration A- 26mm lead space, ammo pack B- 52mm lead space, ammo pack KF 5.0mm pitch formed lead bulk KE 7.5mm pitch formed lead bulk NA Axial lead, bulk	9 Internal code △△ Monolithic type Standard products △Z Multilayer type Standard products △J Multilayer type (Low voltage products) △=Blank space	

外形寸法 EXTERNAL DIMENSIONS

TYPE	Dimensions			テーピング品 Taped product		単品 Bulk Product	
	L	φD	φd	ストレート Straight	ストレート Straight	フォーミング Formed	
単層形050 (Monolithic Type)	3.5max (0.138max)	1.9max (0.075max)	0.45±0.05 (0.018±0.002)				
積層形075 (Multilayer Type)	4.2max (0.165max)	3.2max (0.126max)	0.55±0.05 (0.022±0.002)				
積層形050 (Multilayer Type)	3.2max (0.126max)	2.2max (0.087max)	0.45±0.05 (0.018±0.002)				
積層形025 (Multilayer Type)	2.3max (0.09max)	2.0max (0.079max)					
積層形015 (Multilayer Type)	3.0max (0.118max)	2.5max (0.098max)					

Unit : mm (inch)

概略バリエーション AVAILABLE CAPACITANCE RANGE

Class 1 (Temperature compensating)

WV		50V (UP)					
Temp.char.		CH		RH		UJ	
Type cap.		025		050		050	
[pF]	[pF : 3digits]	025	050	050	050	025	050
1	010						
1.2	1R2						
1.5	1R5						
1.8	1R8						
2.2	2R2						
2.7	2R7						
3.3	3R3						
3.9	3R9						
4.7	4R7						
5.6	5R6						
6.8	6R8						
8.2	8R2						
10	100						
11	110						
12	120						
13	130						
15	150						
16	160						
18	180						
20	200						
22	220						
24	240						
27	270						
30	300						
33	330						
36	360						
39	390						
43	430						
47	470						
51	510						
56	560						
62	620						
68	680						
100	101						
150	151						
220	221						
330	331						
470	471						
680	681						
1000	102						

Class 2 (High dielectric constant)

WV		50V (UP)						35V (GP)		25V (TP)		16V (EP)		10V (LP)	
Temp.char.		B		F		B		F		B		F		B	
Type cap.		025		050		075		015		025		050		015	
[pF]	[pF : 3digits]	025	050	075	015	025	050	075	015	025	050	015	025	050	015
75	750														
82	820														
91	910														
100	101														
120	121														
150	151														
180	181														
220	221														
270	271														
330	331														
390	391														
470	471														
560	561														
680	681														
820	821														
1000	102														
1200	122														
1500	152														
1800	182														
2200	222														
2700	272														
3300	332														
3900	392														
4700	472														
5600	562														
6800	682														
8200	822														
10000	103														
15000	153														
22000	223														
33000	333														
47000	473														
68000	683														
100000	104														
220000	224														
470000	474														
1000000	105														
2200000	225														
4700000	475														
10000000	106														

※単層タイプの製品につきましては、生産終了予定ですので詳細につきましては最寄の弊社営業窓口までお問い合わせ下さい。

※Since the production of monolithic layer products is scheduled to be discontinued, please contact your nearest sales office if you require any detailed information.

温度特性 Temperature char.	静電容量変化率 Capacitance change	容量許容差 Capacitance Tolerance	Q又はtanδ Q or tan δ	種類 Class
CH	0± 60ppm/°C	D (±0.5pF) M (±20%) K (±10%) J (±5%)	アイテム一覧参照 eng・Refer to the Part number	1
RH	-220± 60ppm/°C			
UJ	-750±120ppm/°C			
SL	+350~- 1000ppm/°C			
△B	±10%	K (±10%)		2
△F	± $\frac{30}{100}$ %	Z (± $\frac{30}{100}$ %)		

※20°Cにおける静電容量を基準。

※Capacitance characteristics measured at 20°C

セクションガイド
Selection Guide

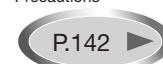
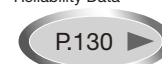
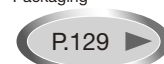
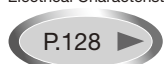
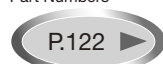
アイテム一覧
Part Numbers

特性図
Electrical Characteristics

梱包
Packaging

信頼性
Reliability Data

使用上の注意
Precautions



etc

TAIYO YUDEN 2008

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CAPACITORS

[単層タイプ Monolithic type]
Class 1

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※Since the production of monolithic layer products is scheduled to be discontinued, please contact your nearest sales office if you require any detailed information.

定 格 電 圧 RatedVoltage (DC)	形 名 Ordering code		EHS (Environmental Hazardous Substances)	温度特性 Temperature characteristics	公 称 静電容量 Capacitance 〔pF〕	容 量 許 容 差 Capacitance tolerance	Q or tan δ	絶縁抵抗 Insulation resistance							
50V	UP050△010M-○		RoHS	CH RH SL	1.0	±20%	Q≥400+20C (C:公称静電容量 capacitance〔pF〕) ただしRHは 16pF以上は Q≥500 but Q≥500 at 16pF or over of characteristic RH	10000MΩmin							
	UP050△1R2M-○		RoHS		1.2										
	UP050△1R5M-○		RoHS		1.5										
	UP050△1R8M-○		RoHS		1.8										
	UP050△2R2K-○		RoHS	CH RH UJ SL	2.2	±10%			Q≥400+20C (C:公称静電容量 capacitance〔pF〕) ただしRHは 16pF以上は Q≥500 but Q≥500 at 16pF or over of characteristic RH	10000MΩmin					
	UP050△2R7K-○		RoHS		2.7										
	UP050△3R3K-○		RoHS		3.3										
	UP050△3R9K-○		RoHS		3.9										
	UP050△4R7K-○		RoHS		4.7										
	UP050△5R6K-○		RoHS		5.6										
	UP050△6R8K-○		RoHS		6.8										
	UP050△8R2K-○		RoHS		8.2										
	UP050△100J-○		RoHS		10										
	UP050△110J-○		RoHS		11										
	UP050△120J-○		RoHS		12										
	UP050△130J-○		RoHS		13										
	UP050△150J-○		RoHS		15										
	UP050△160J-○		RoHS		16										
	UP050△180J-○		RoHS		18										
	UP050△200J-○		RoHS	CH、UJ、SL	20	±5%					Q≥500	10000MΩmin			
	UP050△220J-○		RoHS	UJ SL	22										
	UP050△240J-○		RoHS		24										
	UP050△270J-○		RoHS		27										
	UP050△300J-○		RoHS		30										
	UP050SL330J-○		RoHS	SL	33								±5%	Q≥500	10000MΩmin
	UP050SL360J-○		RoHS		36										
	UP050SL390J-○		RoHS		39										
	UP050SL430J-○		RoHS		43										
UP050SL470J-○		RoHS	47												
UP050SL510J-○		RoHS	51												
UP050SL560J-○		RoHS	56												
UP050SL620J-○		RoHS	62												
UP050SL680J-○		RoHS	68												

形名の△には温度特性、○にはリード形状分類記号が入ります。

△Please specify the temperature characteristics code and ○ lead configuration code.

[積層025タイプ Multilayer 025 Type]

Class 1

定 格 電 圧 RatedVoltage (DC)	形 名 Ordering code		EHS (Environmental Hazardous Substances)	温度特性 Temperature characteristics	公 称 静電容量 Capacitance [pF]	容 量 許 容 差 Capacitance tolerance	Q or tan δ	絶縁抵抗 Insulation resistance
50V	UP025△010D-○ Z		RoHS	CH SL	1.0	±0.5pF	Q≧400+20C	10000MΩmin
	UP025△1R2D-○ Z		RoHS		1.2			
	UP025△1R5D-○ Z		RoHS		1.5			
	UP025△1R8D-○ Z		RoHS		1.8			
	UP025△2R2D-○ Z		RoHS		2.2			
	UP025△2R7D-○ Z		RoHS		2.7			
	UP025△3R3D-○ Z		RoHS		3.3			
	UP025△3R9D-○ Z		RoHS		3.9			
	UP025△4R7D-○ Z		RoHS		4.7			
	UP025△5R6K-○ Z		RoHS		5.6	±10%		
	UP025△6R8K-○ Z		RoHS		6.8			
	UP025△8R2K-○ Z		RoHS		8.2			
	UP025△100J-○ Z		RoHS		10			
	UP025△120J-○ Z		RoHS		12			
	UP025△150J-○ Z		RoHS		15			
	UP025△180J-○ Z		RoHS		18			
	UP025△220J-○ Z		RoHS		22			
	UP025△270J-○ Z		RoHS		27			
	UP025△330J-○ Z		RoHS		33			
	UP025△390J-○ Z		RoHS		39			
	UP025△470J-○ Z		RoHS		47			
	UP025△560J-○ Z		RoHS		56			
	UP025△680J-○ Z		RoHS		68			
	UP025△820J-○ Z		RoHS		82			
	UP025CH101J-○ Z		RoHS	CH	100	Q≧1000		
	UP025CH151J-○ Z		RoHS		150			
	UP025CH221J-○ Z		RoHS		220			
	UP025CH331J-○ Z		RoHS		330			
	UP025CH471J-○ Z		RoHS		470			
	UP025CH681J-○ Z		RoHS		680			
	UP025CH102J-○ Z		RoHS		1000			

形名の△には温度特性、○にはリード形状分類記号が入ります。

△Please specify the temperature characteristics code and ○ lead configuration code.

アイテム一覧 PART NUMBERS

[積層015タイプ Multilayer 015type]
Class 2

定格電圧 Rated Voltage (DC)	形名 Ordering Code		EHS (Environmental Hazardous Substances)	温度特性 Temperature characteristics	公称 静電容量 Capacitance [pF]	容量 許容差 Capacitance tolerance	Q or tan δ	絶縁抵抗 Insulation resistance
25V	TP015 B103K-○ Z		RoHS	B	10000	±10%	$\tan \delta \leq 3.5\%$	5000M Ω min
16V	EP015 B104K-○ Z		RoHS		100000		$\tan \delta \leq 5.0\%$	1000M Ω min
50V	UP015 F103Z-○ Z		RoHS	F	10000	+80 -20 %	$\tan \delta \leq 7.5\%$	1000M Ω min
16V	EP015 F104Z-○ Z		RoHS		100000		$\tan \delta \leq 10.0\%$	

形名の△には温度特性、○にはリード形状分類記号が入ります。

△Please specify the temperature characteristics code and ○ lead configuration code.

[積層025タイプ Multilayer 025 Type]
Class 2

定格電圧 Rated Voltage (DC)	形名 Ordering code		EHS (Environmental Hazardous Substances)	温度特性 Temperature characteristics	公称 静電容量 Capacitance [pF]	容量 許容差 Capacitance tolerance	Q or tan δ	絶縁抵抗 Insulation resistance
50V	UP025 B101K-○ Z		RoHS	B	100	±10%	$\tan \delta \leq 3.5\%$	5000M Ω min
	UP025 B121K-○ Z		RoHS		120			
	UP025 B151K-○ Z		RoHS		150			
	UP025 B181K-○ Z		RoHS		180			
	UP025 B221K-○ Z		RoHS		220			
	UP025 B271K-○ Z		RoHS		270			
	UP025 B331K-○ Z		RoHS		330			
	UP025 B391K-○ Z		RoHS		390			
	UP025 B471K-○ Z		RoHS		470			
	UP025 B561K-○ Z		RoHS		560			
	UP025 B681K-○ Z		RoHS		680			
	UP025 B821K-○ Z		RoHS		820			
	UP025 B102K-○ Z		RoHS		1000			
	UP025 B122K-○ Z		RoHS		1200			
	UP025 B152K-○ Z		RoHS		1500			
	UP025 B222K-○ Z		RoHS		2200			
	UP025 B332K-○ Z		RoHS		3300			
	UP025 B472K-○ Z		RoHS		4700			
	UP025 B682K-○ Z		RoHS		6800			
	UP025 B103K-○ Z		RoHS		10000			
	UP025 B153K-○ Z		RoHS		15000			
	UP025 B223K-○ Z		RoHS		22000			
	UP025 B333K-○ Z		RoHS		33000			
	UP025 B473K-○ Z		RoHS		47000		$\tan \delta \leq 5.0\%$	1000M Ω min
	UP025 B683K-○ Z		RoHS		68000			
50V	UP025 B104K-○ Z		RoHS		100000	+80 -20 %	$\tan \delta \leq 7.5\%$	1000M Ω min
	UP025 F103Z-○ Z		RoHS	F	10000			
	UP025 F223Z-○ Z		RoHS		22000			
	UP025 F473Z-○ Z		RoHS		47000			
16V	UP025 F104Z-○ Z		RoHS		100000	±20%	$\tan \delta \leq 3.5\%$	5000M Ω min
	EP025 B122M-○ J		RoHS	B	1200			
	EP025 B152M-○ J		RoHS		1500			
	EP025 B182M-○ J		RoHS		1800			
	EP025 B222M-○ J		RoHS		2200			
	EP025 B272M-○ J		RoHS		2700			
	EP025 B332M-○ J		RoHS		3300			
	EP025 B392M-○ J		RoHS		3900			
	EP025 B472M-○ J		RoHS		4700			
	EP025 B562M-○ J		RoHS		5600			
	EP025 B682M-○ J		RoHS		6800			
	EP025 B822M-○ J		RoHS		8200			
	EP025 B103M-○ J		RoHS		10000			
	EP025 B123M-○ J		RoHS		12000			
	EP025 B153M-○ J		RoHS		15000			
	EP025 B183M-○ J		RoHS		18000			
	EP025 B223M-○ J		RoHS		22000			
25V	TP025 F103Z-○ J		RoHS	F	10000	+80 -20 %	$\tan \delta \leq 7.5\%$	1000M Ω min
	TP025 F223Z-○ J		RoHS		22000			
	TP025 F473Z-○ J		RoHS		47000			

形名の△には温度特性、○にはリード形状分類記号が入ります。

△Please specify the temperature characteristics code and ○ lead configuration code.

[積層タイプ Multilayer type]

Class 1

定 格 電 圧 Rated Voltage (DC)	形 名 Ordering code		EHS (Environmental Hazardous Substances)	温度特性 Temperature characteristics	公 称 静電容量 Capacitance 〔pF〕	容 量 許 容 差 Capacitance tolerance	Q or tan δ	絶縁抵抗 Insulation resistance
50V	UP050CH220J-○ Z		RoHS	CH	22	± 5%	Q≥400+20C	10000MΩmin
	★UP050CH240J-○ Z		RoHS		24			
	UP050CH270J-○ Z		RoHS		27			
	★UP050CH300J-○ Z		RoHS		30			
	UP050CH330J-○ Z		RoHS		33			
	★UP050CH360J-○ Z		RoHS		36			
	UP050CH390J-○ Z		RoHS		39			
	★UP050CH430J-○ Z		RoHS		43			
	UP050CH470J-○ Z		RoHS		47			
	★UP050CH510J-○ Z		RoHS		51			
	UP050CH560J-○ Z		RoHS		56			
	★UP050CH620J-○ Z		RoHS		62			
	UP050CH680J-○ Z		RoHS		68			
	★UP050CH750J-○ Z		RoHS		75			
	★UP050CH820J-○ Z		RoHS		82			
	★UP050CH910J-○ Z		RoHS		91			
	UP050CH101J-○ Z		RoHS		100			
	★UP050CH111J-○ Z		RoHS		110			
	★UP050CH121J-○ Z		RoHS		120			
	★UP050CH131J-○ Z		RoHS		130			
	UP050CH151J-○ Z		RoHS		150			
	★UP050CH161J-○ Z		RoHS		160			
	★UP050CH181J-○ Z		RoHS		180			
	★UP050CH201J-○ Z		RoHS		200			
	UP050CH221J-○ Z		RoHS		220			
	★UP050CH241J-○ Z		RoHS		240			
	★UP050CH271J-○ Z		RoHS		270			
	★UP050CH301J-○ Z		RoHS		300			
	UP050CH331J-○ Z		RoHS		330			
	★UP050CH361J-○ Z		RoHS		360			
	★UP050CH391J-○ Z		RoHS		390			
	★UP050CH431J-○ Z		RoHS		430			
	UP050CH471J-○ Z		RoHS		470			
	★UP050CH511J-○ Z		RoHS		510			
	★UP050CH561J-○ Z		RoHS		560			
	★UP050CH621J-○ Z		RoHS		620			
	UP050CH681J-○ Z		RoHS		680			
	★UP050CH751J-○ Z		RoHS		750			
	★UP050CH821J-○ Z		RoHS		820			
	★UP050CH911J-○ Z		RoHS		910			
	UP050CH102J-○ Z		RoHS		1000			

形名の△には温度特性、○にはリード形状分類記号が入ります。 ★：オプション対応

△Please specify the temperature characteristics code and ○ lead configuration code.

★：Option

[単層タイプ Monolithic type]

Class 2

※単層タイプの製品につきましては、生産終息予定ですので詳細につきましては最寄の弊社営業窓口までお問い合わせ下さい。

※Since the production of monolithic layer products is scheduled to be discontinued, please contact your nearest sales office if you require any detailed information.

定 格 電 圧 Rated Voltage (DC)	形 名 Ordering code		EHS (Environmental Hazardous Substances)	温度特性 Temperature characteristics	公 称 静電容量 Capacitance [pF]	容 量 許 容 差 Capacitance tolerance	Q or $\tan \delta$	絶縁抵抗 Insulation resistance
50V	UP050 B750K-○		RoHS	B	75	±10%	$\tan \delta \leq 1.5\%$	10000M Ω min
	UP050 B820K-○		RoHS		82			
	UP050 B910K-○		RoHS		91			
	UP050 B101K-○		RoHS		100			
	UP050 B121K-○		RoHS		120			
	UP050 B151K-○		RoHS		150			
	UP050 B181K-○		RoHS		180			
	UP050 B221K-○		RoHS		220			
	UP050 B271K-○		RoHS		270			
	UP050 B331K-○		RoHS		330			
	UP050 B391K-○		RoHS		390			
	UP050 B471K-○		RoHS		470			
	UP050 B561K-○		RoHS		560		$\tan \delta \leq 2.5\%$	1000M Ω min
	UP050 B681K-○		RoHS		680			
	UP050 B821K-○		RoHS		820			
	UP050 B102K-○		RoHS		1000			
25V	TP050 F103Z-○		RoHS	F	10000	± $\frac{80}{20}\%$	$\tan \delta \leq 7.5\%$	1000M Ω min
	TP050 F223Z-○		RoHS		22000			

形名の□には容量許容差、○にはリード形状分類記号が入ります。

□Please specify the capacitance tolerance code and ○ lead configuration code.

[積層タイプ Multilayer type]

Class 2

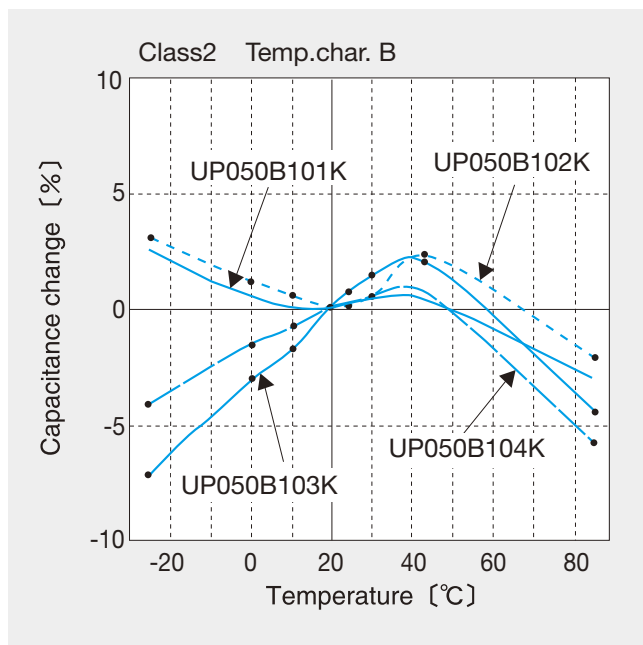
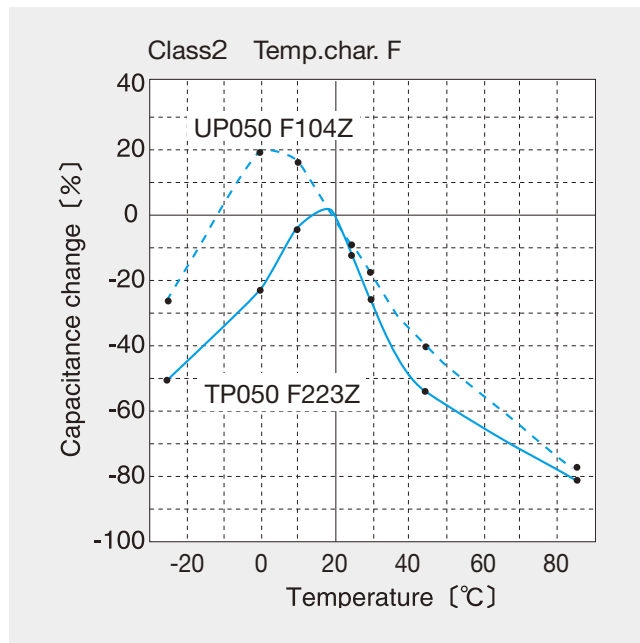
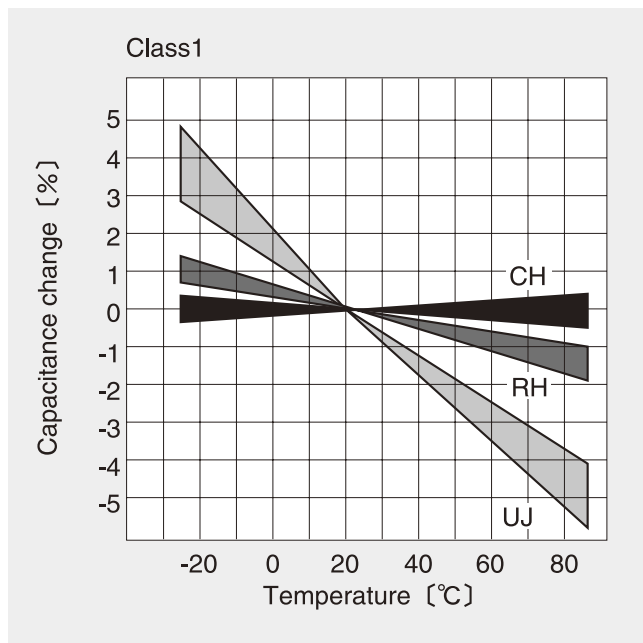
定格電圧 Rated Voltage (DC)	形名 Ordering code		EHS (Environmental Hazardous Substances)	温度特性 Temperature characteristics	公称 静電容量 Capacitance [pF]	容量 許容差 Capacitance tolerance	Q or tan δ	絶縁抵抗 Insulation resistance
50V	★ UP050 B122K-○ Z		RoHS	B	1200	±10%	tan $\delta \leq 3.5\%$	5000M Ω min
	UP050 B152K-○ Z		RoHS		1500			
	★ UP050 B182K-○ Z		RoHS		1800			
	UP050 B222K-○ Z		RoHS		2200			
	★ UP050 B272K-○ Z		RoHS		2700			
	UP050 B332K-○ Z		RoHS		3300			
	★ UP050 B392K-○ Z		RoHS		3900			
	UP050 B472K-○ Z		RoHS		4700			
	★ UP050 B562K-○ Z		RoHS		5600			
	UP050 B682K-○ Z		RoHS		6800			
	★ UP050 B822K-○ Z		RoHS		8200			
	UP050 B103K-○ Z		RoHS		10000			
	★ UP050 B123K-○ Z		RoHS		12000			
	UP050 B153K-○ Z		RoHS		15000			
	★ UP050 B183K-○ Z		RoHS		18000			
	UP050 B223K-○ Z		RoHS		22000			
	★ UP050 B273K-○ Z		RoHS		27000			
	UP050 B333K-○ Z		RoHS		33000			
	★ UP050 B393K-○ Z		RoHS		39000			
	UP050 B473K-○ Z		RoHS		47000			
	★ UP050 B563K-○ Z		RoHS		56000		tan $\delta \leq 5.0\%$	1000M Ω min
	UP050 B683K-○ Z		RoHS		68000			
	★ UP050 B823K-○ Z		RoHS		82000			
	UP050 B104K-○ Z		RoHS		100000			
	UP050 B224K-○ Z		RoHS		220000			500M Ω min
	UP050 B474K-○ Z		RoHS		470000			200M Ω min
16V	EP050 B105K-○ Z		RoHS	F	1000000	+80% -20%	tan $\delta \leq 7.5\%$	100M Ω min
	EP050 B225K-○ Z		RoHS		2200000			50M Ω min
	EP050 B475K-○ Z		RoHS		4700000			20M Ω min
	EP050 B106K-○ Z		RoHS		10000000		tan $\delta \leq 12.5\%$	
50V	UP050 F103Z-○ Z		RoHS		10000		tan $\delta \leq 7.5\%$	1000M Ω min
	UP050 F223Z-○ Z		RoHS		22000			
	UP050 F473Z-○ Z		RoHS		47000		tan $\delta \leq 10.0\%$	500M Ω min
	UP050 F104Z-○ Z		RoHS		100000			
	UP050 F224Z-○ Z		RoHS		220000		tan $\delta \leq 15\%$	250M Ω min
	UP050 F474Z-○ Z		RoHS		470000			
16V	EP050 F105Z-○ Z		RoHS		1000000		tan $\delta \leq 17.5\%$	125M Ω min
	EP050 F225Z-○ Z		RoHS		2200000			
10V	LP050 F475Z-○ Z		RoHS		4700000		tan $\delta \leq 17.5\%$	50M Ω min
	LP050 F106Z-○ Z		RoHS		10000000			25M Ω min
50V	UP075 B105K-○		RoHS	B	1000000	±10%	tan $\delta \leq 5.0\%$	100M Ω min
35V	GP075 B225K-○		RoHS		2200000		tan $\delta \leq 7.5\%$	50M Ω min
	GP075 B475K-○		RoHS		4700000			
25V	TP075 B106K-○		RoHS	F	10000000	+80% -20%	tan $\delta \leq 12.5\%$	20M Ω min
35V	GP075 F106Z-○		RoHS		10000000		tan $\delta \leq 17.5\%$	25M Ω min

形名の△には温度特性、○にはリード形状分類記号が入ります。 ★：オプション対応

△Please specify the temperature characteristics code and ○ lead configuration code.

★：Option

・静電容量－温度特性 Capacitance -vs- Temperature Characteristics

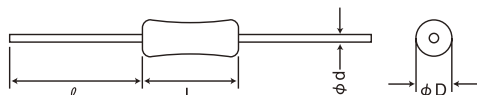


①最小受注単位数 Minimum Quantity

形式 Type	リード形状記号 Lead configuration code	最小受注単位数(PCS) Minimum Quantity	
		袋づめ Bulk	テーピング Taping
積層形 Multilayer type (075, 050, 025, 015)	A- (26mm幅) 1.024 inch wide	—	2000 (075type) 3000 (050type) 5000 (015, 025type)
	B- (52mm幅) 2.047 inches wide	—	2000 (075type) 3000 (050type) 5000 (015, 025type)
	NA	1000	—
	KE (075type) KF (015, 025, 050type)	3000, 4000 (015, 025 type)	—
単層形 Monolithic type (050)	A- (26mm幅) 1.024 inch wide	—	4000
	B- (52mm幅) 2.047 inches wide	—	4000
	NA	1000	—
	KF	3000	—

②製品単品形状 Dimensions of Bulk Products

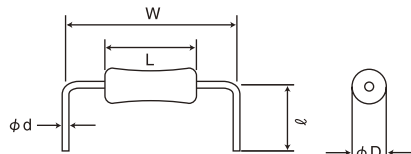
・NA形状 NA configuration



形式 Type	寸法 Dimensions (mm)			
	ϕD	L	ϕd	ℓ
積層形 015 Multilayer type	2.5max (0.098)	3.0max (0.118)	0.45±0.05 (0.018±0.002)	20.0min (0.787)
積層形 025 Multilayer type	2.0max (0.079)	2.3max (0.09)	0.45±0.05 (0.018±0.002)	20.0min (0.787)
積層形 050 Multilayer type	2.2max (0.087)	3.2max (0.126)	0.45±0.05 (0.018±0.002)	20.0min (0.787)
積層形 075 Multilayer type	3.2max (0.126)	4.2max (0.165)	0.55±0.05 (0.022±0.002)	20.0min (0.787)
単層形050 Monolithic type	1.9max (0.075)	3.5max (0.138)	0.45±0.05 (0.018±0.002)	20.0min (0.787)

Unit : mm (inch)

・KF/KE形状 KF/KE configuration

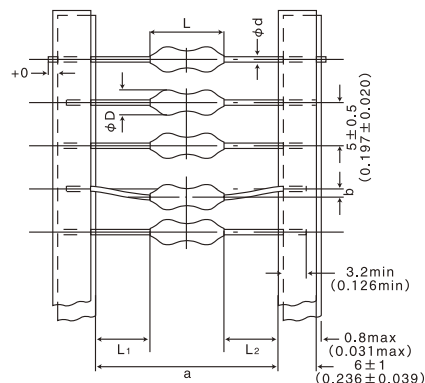


形式 Type	リード形状記号 Lead configuration code	寸法 Dimensions (mm)				
		ϕD	L	W	ϕd	ℓ
積層形 015 Multilayer type	KF	2.5max (0.098max)	3.0max (0.118max)	5.0±0.5 (0.197±0.020)	0.45±0.05 (0.018±0.002)	6.5±0.5 (0.256±0.020)
積層形 025 Multilayer type	KF	2.0max (0.079max)	2.3max (0.09max)	5.0±0.5 (0.197±0.020)	0.45±0.05 (0.018±0.002)	6.5±0.5 (0.256±0.020)
積層形 050 Multilayer type	KF	2.2max (0.087max)	3.2max (0.126max)	5.0±0.5 (0.197±0.020)	0.45±0.05 (0.018±0.002)	6.5±0.5 (0.256±0.020)
積層形 075 Multilayer type	KE	3.2max (0.126max)	4.2max (0.165max)	7.5±0.5 (0.295±0.020)	0.55±0.05 (0.022±0.002)	6.5±0.5 (0.256±0.020)
単層形050 Monolithic type	KF	1.9max (0.075max)	3.5max (0.138max)	5.0±0.5 (0.197±0.020)	0.45±0.05 (0.018±0.002)	6.5±0.5 (0.256±0.020)

Unit : mm (inch)

③テーピング寸法 Taping Dimensions

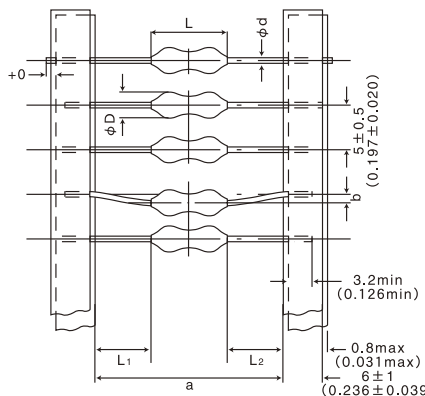
A- (a : 26mm幅) 形状 (a : 1.024 inch wide) configuration



形式 Type	寸法 Dimensions						最小挿入 ピッチ Minimum insertion pitch
	ϕD	L	a	b	$ L_1 - L_2 $	ϕd	
積層形 015 Multilayer type	2.5max (0.098max)	3.0max (0.118max)	$26^{+0.5}_{-0}$ (1.024 ^{+0.020} -0)	0.8以下 (0.031 or less)	0.5max (0.020max)	0.45±0.05 (0.018±0.002)	5.0 (0.197)
積層形 025 Multilayer type	2.0max (0.079max)	2.3max (0.09max)				0.45±0.05 (0.018±0.002)	
積層形 050 Multilayer type	2.2max (0.087max)	3.2max (0.126max)				0.45±0.05 (0.018±0.002)	
積層形 075 Multilayer type	3.2max (0.126max)	4.2max (0.165max)				0.55±0.05 (0.022±0.002)	7.5 (0.295)
単層形050 Monolithic type	1.9max (0.075max)	3.5max (0.138max)				0.45±0.05 (0.018±0.002)	5.0 (0.197)

Unit : mm (inch)

B- (a : 52mm幅) 形状 (a : 2.047 inches wide) configuration



形式 Type	寸法 Dimensions						最小挿入 ピッチ Minimum insertion pitch
	ϕD	L	a	b	$ L_1 - L_2 $	ϕd	
積層形 015 Multilayer type	2.5max (0.098max)	3.0max (0.118max)	52^{+2}_{-1} (2.047 ^{+0.075} -0.039)	1.2以下 (0.047 or less)	1.0max (0.039max)	0.45±0.05 (0.018±0.002)	5.0 (0.197)
積層形 025 Multilayer type	2.0max (0.079max)	2.3max (0.09max)				0.45±0.05 (0.018±0.002)	
積層形 050 Multilayer type	2.2max (0.087max)	3.2max (0.126max)				0.45±0.05 (0.018±0.002)	
積層形 075 Multilayer type	3.2max (0.126max)	4.2max (0.165max)				0.55±0.05 (0.022±0.002)	7.5 (0.295)
単層形050 Monolithic type	1.9max (0.075max)	3.5max (0.138max)				0.45±0.05 (0.018±0.002)	5.0 (0.197)

Unit : mm (inch)

※075Typeはラジアルテーピングもオプション対応可能。

AXIAL LEADED CERAMIC CAPACITORS

Item		Specified Value			Test Methods and Remarks
		Temperature Compensating (Class1)	High Permittivity (Class2)		
		Multilayer type	Multilayer type (Characteristics:B)	Multilayer type (Characteristics:F)	
1. Operating Temperature Range		-25~+85℃			
2. Storage Temperature Range		-25~+85℃			
3. Rated Voltage		50VDC	16VDC、25VDC、35VDC、50VDC	10VDC、16VDC、25VDC、35VDC、50VDC	
4. Withstanding Voltage	Between terminals	No abnormality			Applied voltage: Rated Voltage×3 (Class 1) Rated Voltage×2.5 (Class 2) Duration: 1 to 5 sec. Charge/discharge current: 50mA max. (Class 1,2)
	Between terminals and body	No abnormality			Metal globule method Applied voltage: Rated Voltage×2.5 Duration: 1 to 5 sec. Charge/Discharge current : 50mA max.
5. Insulation Resistance		10000MΩmin.	Rated Iovoltage:16VDC B: 100000pF :1000MΩmin 1000000pF :100MΩ min 2200000pF :50MΩ min 4700000pF~10000000pF :20MΩ min 1200pF~22000pF (Item:ΔJ):5000MΩmin Rated Iovoltage:25VDC B: 10000pF :5000MΩmin 10000000pF :20MΩ min Rated Iovoltage:35VDC B: 22000000pF :50MΩ min 47000000pF :20MΩ min Rated Iovoltage:50VDC B: 100pF~39000pF :5000MΩ min 47000pF~100000pF :1000MΩ min 2200000pF :500MΩ min 4700000pF :200MΩ min 10000000pF :100MΩ min	Rated Iovoltage:10VDC F: 47000000pF :50MΩ min 10000000pF :25MΩ min Rated Iovoltage:16VDC F: 100000pF :1000MΩ min 2200000pF :125MΩ min Rated voltage:25VDC F: 10000pF~47000pF (ItemΔJ) :1000MΩ min Rated voltage:35VDC F: 10000000pF :25MΩ min Rated voltage:50VDC F: 10000pF~100000pF :1000MΩ min 220000pF~470000pF :500MΩ min 1000000pF :250MΩ min	Applied voltage: Rated voltage Duration : 60±5 sec.
6. Capacitance :		±0.5pF ± 5% ± 10%	Rated Iovoltage:16VDC B: ±10%,±20% (ItemΔJ) Rated Iovoltage:25VDC B: ±10% Rated Iovoltage:35VDC B: ±10% Rated Iovoltage:50VDC B: ±10%	Rated Iovoltage:10VDC F: +80% -20% Rated Iovoltage:16VDC F: +80% -20% Rated Iovoltage:25VDC F: +80% -20% Rated Iovoltage:35VDC F: +80% -20% Rated Iovoltage:50VDC F: +80% -20%	Measuring frequency 1MHz±10% (Class 1: C≤1000pF) 1kHz±10% (Class 1: C>1000pF) 1kHz±10% (Class 2) Measuring voltage 1.0±0.5Vrms (Class 1: C≤1000pF) 1.0±0.2Vrms (Class 1: C>1000pF) 1.0±0.2Vrms (Class 2) Measuring temperature: 20℃ Bias application: None
7. Q or Tangent of Loss Angle		30pF or under : Q≥400+20C 33pF or over : Q≥1000 C:Nominal Capacitance :[pF]	Rated Iovoltage:16VDC B: 1200pF~22000pF (ItemΔJ) :3.5%max 100000pF :5.0%max 1000000pF :5.0% max 2200000pF~4700000pF :7.5% max 10000000pF :12.5% max Rated Iovoltage:25VDC B: 10000pF :3.5%max 10000000pF :12.5% max Rated Iovoltage:35VDC B: 22000000pF~47000000pF :7.5% max Rated Iovoltage:50VDC B: 100pF~39000pF :3.5% max 47000pF ~1000000pF :5.0% max	Rated Iovoltage:10VDC F: 47000000pF~10000000pF :17.5% max Rated Iovoltage:16VDC F: 100000pF :10.0% max 2200000pF :15.0% max Rated Iovoltage:25VDC F: 10000pF~47000pF (ItemΔJ) :7.5% max Rated Iovoltage:35VDC F: 10000000pF :17.5% max Rated Iovoltage:50VDC F: 10000pF~100000pF :7.5% max 220000pF~470000pF :10.0% max 1000000pF :15.0% max	
8. Capacitance : Change due to Temperature or Rate of Capacitance Change		(When voltage is not applied) CH : 0±60 SL : -350~+1000 [ppm/℃]	Rated Iovoltage:16VDC B: ±10% Rated Iovoltage:25VDC B: ±10% Rated Iovoltage:35VDC B: ±10% Rated Iovoltage:50VDC B: ±10%	Rated Iovoltage:10VDC F: +30% -85% Rated Iovoltage:16VDC F: +30% -85% Rated Iovoltage:25VDC F: +30% -85% Rated Iovoltage:35VDC F: +30% -85% Rated Iovoltage:50VDC F: +30% -85%	Measurement of capacitance at 20℃ and 85℃, -25℃ shall be made to calculate temperature characteristic by the following equation. (Class 1) $\frac{(C_{85}-C_{20})}{C_{20} \times \Delta T} \times 10^6$ (ppm/℃) Change of maximum capacitance deviation in step 1 to 5 (Class 2) Temperature at step 1: 20℃ Temperature at step 4: 85℃ Temperature at step 2: -25℃ Temperature at step 5: 20℃ Temperature at step 3: 20℃ (Reference temperature)

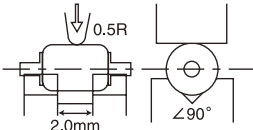
Withstanding voltage is also referred to as "voltage proof" under IEC specifications.

AXIAL LEADED CERAMIC CAPACITORS

Item		Specified Value			Test Methods and Remarks						
		Temperature Compensating (Class1)	High Permittivity (Class2)								
		Multilayer type	Multilayer type (Characteristics:B)	Multilayer type (Characteristics:F)							
9. Terminal Strength	Tensile	No abnormalities, such as cuts or looseness of terminals.			Apply the stated tensile force progressively in the direction to draw terminal. <table><tr><td>Nominal wire diameter [mm]</td><td>Tensile force [N]</td><td>Duration [s]</td></tr><tr><td>0.45</td><td>19.6</td><td>5</td></tr></table>	Nominal wire diameter [mm]	Tensile force [N]	Duration [s]	0.45	19.6	5
	Nominal wire diameter [mm]	Tensile force [N]	Duration [s]								
0.45	19.6	5									
Torsional	No abnormalities, such as cuts or looseness of terminals.			Suspend a mass at the end the terminal, incline the body through angle of 90° and return it to initial position. This operation is done over a period of 5 sec. Then second bend in the opposite direction shall be made. Number of bends : 2 times <table><tr><td>Nominal wire diameter [mm]</td><td>Bending force [N]</td><td>Mass weight [kg]</td></tr><tr><td>0.45</td><td>2.45</td><td>0.25</td></tr></table>	Nominal wire diameter [mm]	Bending force [N]	Mass weight [kg]	0.45	2.45	0.25	
Nominal wire diameter [mm]	Bending force [N]	Mass weight [kg]									
0.45	2.45	0.25									
10. Resistance to Vibration		Appearance : No significant abnormality Withstanding Voltage : No abnormality Capacitance : Within ±5% 4.7pF or under :Within ±0.5pF 5.6pF~8.2pF :Within ±10% 10pF or over :Within ±5% Q: 30pF or under : Q≥400+20C 33pF or over : Q≥1000 Insulation resistance : 10000MΩ min. C:Nominal Capacitance :[pF]	Appearance : No significant abnormality Withstanding Voltage : No abnormality Rated Voltage:16VDC B Capacitance :Within ±10% 1200pF~22000pF (ItemΔJ) :Within ±20% 100000pF~1000000pF :Within ±10% tanδ: 1200pF~22000pF (ItemΔJ) :3.5%max 100000pF :5.0%max 1000000pF :5.0% max 2200000pF~4700000pF :7.5% max 1000000pF :12.5% max Insulation Resistance: 1200pF~22000pF (ItemΔJ) :5000MΩmin 100000pF :1000MΩmin 1000000pF :100MΩmin 2200000pF :50MΩmin 4700000pF~10000000pF :20MΩmin Rated Voltage:25VDC B Capacitance :Within ±10% tanδ: 10000pF :3.5%max 1000000pF :12.5%max Insulation Resistance: 10000pF :5000MΩmin 1000000pF :20MΩmin Rated Voltage:35VDC B Capacitance :Within ±10% tanδ: 2200000pF~4700000pF :7.5%max 2200000pF :50MΩmin 4700000pF :20MΩmin Rated Voltage:50VDC B Capacitance :Within ±10% tanδ: 100pF~39000pF :3.5% max 47000pF~1000000pF :5.0% max Insulation Resistance: 100pF~39000pF :5000MΩ min 47000pF~100000pF :1000MΩ min 220000pF :50MΩ min 470000pF :20MΩ min 1000000pF :100MΩ min	Appearance : No significant abnormality Withstanding Voltage : No abnormality Rated Voltage:10VDC F Capacitance :Within+80-20 % tanδ: 4700000pF~10000000pF :17.5% max Insulation Resistance: 4700000pF :50MΩ min 10000000pF :25MΩ min Rated Voltage:16VDC F Capacitance :Within+80-20 % tanδ: 100000pF :10.0%max 2200000pF :15.0% max Insulation Resistance: 100000pF :1000MΩmin 2200000pF :125MΩmin Rated Voltage:25VDC F Capacitance :Within+80-20 % tanδ: 10000pF~47000pF (ItemΔJ) :7.5%max Insulation Resistance: 10000pF~47000pF (ItemΔJ) :1000MΩmin Rated Voltage:35VDC F Capacitance :Within+80-20 % tanδ: 1000000pF :17.5%max Insulation Resistance: 1000000pF :25MΩmin Rated Voltage:50VDC F Capacitance :Within+80-20 % tanδ: 10000pF~100000pF :7.5%max 220000pF~470000pF :10.0%max 1000000pF :15.0%max Insulation Resistance: 10000pF~100000pF :1000MΩmin 220000pF~470000pF :500MΩmin 1000000pF :250MΩmin	According to JIS C 5102 clause 8.2 Vibration type: A Directions: 2 hrs each in X, Y and Z directions Total: 6 hrs Frequency range: 10 to 55 to 10Hz (1min) Amplitude: 1.5 mm Mounting method: Soldering onto the PC board						

Withstanding voltage is also referred to as "voltage proof" under IEC specifications.

AXIAL LEADED CERAMIC CAPACITORS

Item	Specified Value			Test Methods and Remarks
	Temperature Compensating (Class1)	High Permittivity (Class2)		
	Multilayer type	Multilayer type (Characteristics:B)	Multilayer type (Characteristics:F)	
11. Free Fall	Appearance : No significant abnormality Withstanding Voltage : No abnormality Capacitance : 4.7pF or under :Within ±0.5pF 5.6pF~8.2pF :Within ±10% 10pF or over :Within ±5% Q: 30pF or under : Q≥400+20C 33pF or over : Q≥1000 Insulation resistance : 10000MΩ min. C:Nominal Capacitance :[pF]	Appearance : No significant abnormality Withstanding Voltage : No abnormality Rated Voltage:16VDC B Capacitance : 1200pF~22000pF (ItemΔJ) :Within±20% 100000pF~10000000pF :Within±10% tanδ: 1200pF~22000pF (ItemΔJ) :3.5% max 100000pF :5.0%max 1000000pF :5.0% max 2200000pF~4700000pF :7.5% max 10000000pF :12.5% max Insulation Resistance: 1200pF~22000pF (ItemΔJ) :5000MΩ min 100000pF :1000MΩ min 1000000pF :100MΩ min 2200000pF :50MΩ min 4700000pF~10000000pF :20MΩ min Rated Voltage:25VDC B Capacitance : Within ±10% tanδ: 10000pF :3.5%max 10000000pF :12.5%max Insulation Resistance: 10000pF :5000MΩ min 10000000pF :20MΩ min Rated Voltage:35VDC B Capacitance : Within ±10% tanδ: 2200000pF~4700000pF :7.5%max Insulation Resistance: 2200000pF :50MΩ min 4700000pF :20MΩ min Rated Voltage:50VDC B Capacitance : Within ±10% tanδ: 100pF~39000pF :3.5%max 47000pF~1000000pF :5.0%max Insulation Resistance: 100pF~39000pF :5000MΩ min 47000pF~100000pF :1000MΩ min 220000pF :500MΩ min 470000pF :200MΩ min 1000000pF :100MΩ min	Appearance : No significant abnormality Withstanding Voltage : No abnormality Rated Voltage:10VDC F Capacitance : Within ± 80 -20 % tanδ: 4700000pF~10000000pF :17.5% max Insulation Resistance: 4700000pF :50MΩ min 10000000pF :25MΩ min Rated Voltage:16VDC F Capacitance : Within ± 80 -20 % tanδ: 100000pF :10.0% max 2200000pF :15.0% max Insulation Resistance: 100000pF :1000MΩ min 2200000pF :125MΩ min Rated Voltage:25VDC F Capacitance : Within ± 80 -20 % tanδ: 10000pF~47000pF (ItemΔJ) :7.5%max Insulation Resistance: 10000pF~47000pF (ItemΔJ) :1000MΩ min Rated Voltage:35VDC F Capacitance : Within ± 80 -20 % tanδ: 10000000pF :17.5% max Insulation Resistance: 10000000pF :25MΩ min Rated Voltage:50VDC F Capacitance : Within ± 80 -20 % tanδ: 10000pF~100000pF :7.5% max 220000pF~470000pF :10.0% max 1000000pF :15.0% max Insulation Resistance: 10000pF~100000pF :1000MΩ min 220000pF~470000pF :500MΩ min 1000000pF :250MΩ min	Drop Test: Free fall Impact material: Floor Height: 1 m Total number of drops: 5 times
12. Body Strength	No abnormality such as damage.			Applied force: 19.6N Duration: 5 sec. Speed: Shall attain to specified force in 2 sec.  1.5mm (025type)
13. Solderability	At least 75% of lead surface is covered with new solder.			Solder temperature: 230±5℃ Duration: 2±0.5 sec. (This test may be applicable after 6 months storage.)

Withstanding voltage is also referred to as "voltage proof" under IEC specifications.

AXIAL LEADED CERAMIC CAPACITORS

Item	Specified Value			Test Methods and Remarks																		
	Temperature Compensating (Class1)	High Permittivity (Class2)																				
	Multilayer type	Multilayer type (Characteristics:B)	Multilayer type (Characteristics:F)																			
14. Soldering	Appearance : No significant abnormality Withstanding Voltage : No abnormality Capacitance change : 8.2pF or under :Within ±0.25pF 10pF or over :Within ±2.5% Q: 30pF or under: Q≥400+20C 33pF or over: Q≥1000 Insulation resistance: 10000MΩ min. C:Nominal Capacitance :[pF]	Appearance : No significant abnormality Withstanding Voltage : No abnormality Rated Voltage:16VDC B Capacitance change : 1200pF~22000pF (Item△J) 100000pF : Within ±7.5% 1000000pF~10000000pF : Within ±10.0% tanδ: 1200pF~22000pF (Item△J) : 3.5% max 100000pF : 5.0% max 1000000pF : 5.0% max 2200000pF~4700000pF : 7.5% max 10000000pF : 12.5% max Insulation Resistance: 1200pF~22000pF (Item△J) : 5000MΩ min 100000pF : 1000MΩ min 1000000pF : 100MΩ min 2200000pF : 50MΩ min 4700000pF~10000000pF : 20MΩ min Rated Voltage:25VDC B Capacitance change : 10000pF : Within ±7.5% 10000000pF : Within ±10.0% tanδ: 10000pF : 3.5% max 10000000pF : 12.5% max Insulation Resistance: 10000pF : 5000MΩ min 10000000pF : 20MΩ min Rated Voltage:35VDC B Capacitance change : tanδ: 2200000pF~4700000pF : 7.5% max Insulation Resistance: 2200000pF : 50MΩ min 4700000pF : 20MΩ min Rated Voltage:50VDC B Capacitance change : 100pF~39000pF : Within ±7.5% 47000pF~1000000pF : Within ±10.0% tanδ: 100pF~39000pF : 3.5% max 47000pF~1000000pF : 5.0% max Insulation Resistance: 100pF~39000pF : 5000MΩ min 47000pF~1000000pF : 1000MΩ min 220000pF : 500MΩ min 470000pF : 200MΩ min 1000000pF : 100MΩ min	Appearance : No significant abnormality Withstanding Voltage : No abnormality Rated Voltage:10VDC F Capacitance change : Within ±20.0% tanδ: 4700000pF~10000000pF : 17.5% max Insulation Resistance: 1000000pF : 50MΩ min 10000000pF : 25MΩ min Rated Voltage:16VDC F Capacitance change : Within ±20.0% tanδ: 100000pF : 10.0% max 2200000pF : 15.0% max Insulation Resistance: 100000pF : 1000MΩ min 2200000pF : 125MΩ min Rated Voltage:25VDC F Capacitance change : Within ±20.0% tanδ: 10000pF~47000pF (Item△J) : 7.5% max Insulation Resistance: 10000pF~47000pF (Item△J) : 1000MΩ min Rated Voltage:35VDC F Capacitance change : Within ±20.0% tanδ: 1000000pF : 17.5% max Insulation Resistance: 10000000pF : 25MΩ min Rated Voltage:50VDC F Capacitance change : 10000pF~1000000pF : Within ±20.0% tanδ: 10000pF~100000pF : 7.5% max 220000pF~470000pF : 10.0% max 1000000pF : 15.0% max Insulation Resistance: 10000pF~100000pF : 1000MΩ min 220000pF~470000pF : 500MΩ min 1000000pF : 250MΩ min	Solder temperature: 270±5°C Duration: 5±0.5 sec. Immersed conditions: Inserted into the PC board (with t=1.6mm, hole=1.0mm diameter) Preconditioning: 1 hr of preconditioning at 150±10 °C followed by 48±4 hrs of recovery under the standard condition. Recovery: Recovery for the following period under the standard condition after the test. 24±2 hrs (Class 1) 48±4 hrs (Class 2)																		
15. Resistance to Solvent	No significant abnormality in appearance and legible marking.			According to JIS C 5102 clause 8.7.4. Type of test: Method 1 Solvent temperature: 20 to 25°C Duration: 30±5 sec. Solvent Type: A in Table 23, Isopropyl alcohol																		
16. Thermal Shock	Appearance : No significant abnormality Withstanding Voltage : No abnormality Capacitance change : 8.2pF or under :Within ±0.5pF 10pF or over :Within ±5.0% Q: 8.2pF or under Q≥200+10C 10pF~30pF Q≥275+2.5C 33pF or over: Q≥350 Insulation resistance: 1000MΩ min. C:Nominal Capacitance [pF]	Appearance : No significant abnormality Withstanding Voltage : No abnormality Rated Voltage:16VDC B Capacitance change : 1200pF~22000pF (Item△J) : Within ±12.5% 100000pF : Within ±15.0% 1000000pF~10000000pF : Within ±15.0% tanδ: 1200pF~22000pF (Item△J) : 5.0% max 100000pF : 7.5% max 1000000pF : 7.5% max 2200000pF~4700000pF : 10.0% max 10000000pF : 15.0% max Insulation Resistance: 1200pF~22000pF (Item△J) : 1000MΩ min 100000pF : 500MΩ min 1000000pF : 50MΩ min 2200000pF : 25MΩ min 4700000pF~10000000pF : 5MΩ min Rated Voltage:25VDC B Capacitance change : 10000pF : Within ±12.5% 10000000pF : Within ±15.0% tanδ: 10000pF : 5.0% max 10000000pF : 15.0% max Insulation Resistance: 10000pF : 1000MΩ min 10000000pF : 5MΩ min Rated Voltage:35VDC B Capacitance change : tanδ: 2200000pF~4700000pF : 10.0% max Insulation Resistance: 2200000pF : 25MΩ min 4700000pF : 5MΩ min Rated Voltage:50VDC B Capacitance change : 100pF~39000pF : Within ±12.5% 47000pF~1000000pF : Within ±15.0% tanδ: 100pF~39000pF : 5.0% max 47000pF~1000000pF : 7.5% max Insulation Resistance: 100pF~39000pF : 1000MΩ min 47000pF~1000000pF : 500MΩ min 220000pF : 250MΩ min 470000pF : 100MΩ min 1000000pF : 50MΩ min	Appearance : No significant abnormality Withstanding Voltage : No abnormality Rated Voltage:10VDC F Capacitance change : Within ±30.0% tanδ: 4700000pF~10000000pF : 20.0% max Insulation Resistance: 1000000pF : 10MΩ min 10000000pF : 5MΩ min Rated Voltage:16VDC F Capacitance change : Within ±30.0% tanδ: 100000pF : 15.0% max 2200000pF : 17.5% max Insulation Resistance: 100000pF : 500MΩ min 2200000pF : 25MΩ min Rated Voltage:25VDC F Capacitance change : Within ±30.0% tanδ: 10000pF~47000pF (Item△J) : 12.5% max Insulation Resistance: 10000pF~47000pF (Item△J) : 500MΩ min Rated Voltage:35VDC F Capacitance change : Within ±30.0% tanδ: 1000000pF : 20.0% max Insulation Resistance: 10000000pF : 5MΩ min Rated Voltage:50VDC F Capacitance change : 10000pF~1000000pF : Within ±30% tanδ: 10000pF~100000pF : 12.5% max 220000pF~470000pF : 15.0% max 1000000pF : 17.5% max Insulation Resistance: 10000pF~100000pF : 500MΩ min 220000pF~470000pF : 250MΩ min 1000000pF : 50MΩ min	Conditions for 1 cycle <table><tr><th>Step</th><th>Temperature [°C]</th><th>Duration [min]</th></tr><tr><td>1</td><td>Room temperature</td><td>Within 3</td></tr><tr><td>2</td><td>-25±3</td><td>30±3</td></tr><tr><td>3</td><td>Room temperature</td><td>Within 3</td></tr><tr><td>4</td><td>+85±3</td><td>30±3</td></tr><tr><td>5</td><td>Room temperature</td><td>Within 3</td></tr></table> Number of cycles: 5 Preconditioning: 1 hr of preconditioning at 150 ±10 °C followed by 48±4 hrs of recovery under the standard condition. Recovery: Recovery for the following period under the standard condition after the removal from test chamber. 24±2 hrs (Class 1) 48±4 hrs (Class 2)	Step	Temperature [°C]	Duration [min]	1	Room temperature	Within 3	2	-25±3	30±3	3	Room temperature	Within 3	4	+85±3	30±3	5	Room temperature	Within 3
Step	Temperature [°C]	Duration [min]																				
1	Room temperature	Within 3																				
2	-25±3	30±3																				
3	Room temperature	Within 3																				
4	+85±3	30±3																				
5	Room temperature	Within 3																				

Withstanding voltage is also referred to as "voltage proof" under IEC specifications.

Thermal Shock is also referred to as "rapid change of temperature" under IEC specifications.

AXIAL LEADED CERAMIC CAPACITORS

Item	Specified Value			Test Methods and Remarks
	Temperature Compensating (Class1)	High Permittivity (Class2)		
	Multilayer type	Multilayer type (Characteristics:B)	Multilayer type (Characteristics:F)	
17. Damp Heat (steady state)	Appearance : No significant abnormality Withstanding Voltage : No abnormality	Appearance : No significant abnormality Withstanding Voltage : No abnormality	Appearance : No significant abnormality Withstanding Voltage : No abnormality	emperature: 40±2℃ Humidity: 90 to 95 % RH Duration: 500 ⁺²⁴ ₋₀ hrs Preconditioning: 1 hr of preconditioning at 150 ⁺¹⁰ ₋₁₀ ℃ followed by 48±4 hrs of recovery under the standard condition. Recovery: 24±2 hrs of recovery under the standard condition after the removal from test chamber. (Class 1) : 1 hr of preconditioning at 150 ⁺¹⁰ ₋₀ ℃ followed by 48±4 hrs of recovery under the standard condition after the removal from chamber. (Class 2)
	Capacitance change : 8.2pF or under :Within ±0.5pF 10pF or over :Within ±5.0% Q: :8.2pF or under Q≥200+10C :10pF~30pF Q≥275+2.5C 33pF or over: Q≥350 Insulation resistance: 1000MΩ min. C:Nominal Capacitance [pF]	Rated Voltage:16VDC B Capacitance change : 1200pF~2200pF (ItemΔJ) : Within ±12.5% 100000pF : Within ±15.0% 1000000pF~10000000pF : Within ±15.0% tanδ: 1200pF~22000pF (ItemΔJ) : 5.0% max 100000pF : 7.5% max 1000000pF : 7.5% max 2200000pF~4700000pF : 10.0% max 10000000pF : 15.0% max Insulation Resistance: 1200pF~22000pF (ItemΔJ) : 1000MΩ min 100000pF : 500MΩ min 1000000pF : 50MΩ min 2200000pF : 25MΩ min 4700000pF~10000000pF : 5MΩ min Rated Voltage:25VDC B Capacitance change: 10000pF : Within ±12.5% 10000000pF : Within ±15.0% tanδ: 10000pF : 5.0% max 10000000pF : 15.0% max Insulation Resistance: 10000pF : 1000MΩ min 10000000pF : 5MΩ min Rated Voltage:35VDC B Capacitance change : Within ±15.0% tanδ: 2200000pF~4700000pF : 10.0% max Insulation Resistance: 2200000pF : 25MΩ min 4700000pF : 5MΩ min Rated Voltage:50VDC B Capacitance change : 100pF~39000pF : Within ±12.5% 47000pF~1000000pF : Within ±15.0% tanδ: 100pF~39000pF : 5.0% max 47000pF~1000000pF : 7.5% max Insulation Resistance: 100pF~39000pF : 1000MΩ min 47000pF~100000pF : 500MΩ min 2200000pF : 250MΩ min 470000pF : 100MΩ min 1000000pF : 50MΩ min	Rated Voltage:10VDC F Capacitance change: Within ±30.0% tanδ: 4700000pF~10000000pF : 20.0% max Insulation Resistance: 4700000pF : 10MΩ min 10000000pF : 5MΩ min Rated Voltage:16VDC F Capacitance change: Within ±30.0% tanδ: 100000pF : 15.0% max 2200000pF : 17.5% max Insulation Resistance: 100000pF : 500MΩ min 2200000pF : 25MΩ min Rated Voltage:25VDC F Capacitance change: Within ±30.0% tanδ: 10000pF~47000pF (ItemΔJ) : 12.5% max Insulation Resistance: 10000pF~47000pF (ItemΔJ) : 500MΩ min Rated Voltage:35VDC F Capacitance change: Within ±30.0% tanδ: 10000000pF : 20.0% max Insulation Resistance: 10000000pF : 5MΩ min Rated Voltage:50VDC F Capacitance change : 10000pF~1000000pF : Within ±30% tanδ: 10000pF~100000pF : 12.5% max 220000pF~470000pF : 15.0% max 1000000pF : 17.5% max Insulation Resistance: 10000pF~100000pF : 500MΩ min 220000pF~470000pF : 250MΩ min 1000000pF : 50MΩ min	
18. Loading under Damp Heat	Appearance : No significant abnormality Withstanding Voltage : No abnormality	Appearance : No significant abnormality Withstanding Voltage : No abnormality	Appearance : No significant abnormality Withstanding Voltage : No abnormality	Temperature: 40±2℃ Humidity: 90 to 95 % RH Duration: 500 ⁺²⁴ ₋₀ hrs Applied voltage: Rated voltage Preconditioning: 1 hr of preconditioning at 150 ⁺¹⁰ ₋₀ ℃ followed by 48±4 hrs of recovery under the standard condition. Recovery: 24±2 hrs of recovery under the standard condition after the removal from test chamber. (Class 1) : 1 hr of preconditioning at 150 ⁺¹⁰ ₋₀ ℃ followed by 48±4 hrs of recovery under the standard condition after the removal from chamber. (Class 2)
	Capacitance change : 8.2pF or under :Within ±0.75pF 10pF or over :Within ±7.5% Q: 30pF or under: Q≥100+10/3℃ 33pF or over: Q≥200 Insulation resistance: 500MΩ min. C:Nominal Capacitance [pF]	Rated Voltage:16VDC B Capacitance change : 1200pF~2200pF (ItemΔJ) : Within ±12.5% 100000pF : Within ±15.0% 1000000pF~22000000pF : Within ±15.0% 4700000pF~10000000pF : Within ±22.5% tanδ: 1200pF~22000pF (ItemΔJ) : 5.0% max 100000pF : 7.5% max 1000000pF : 7.5% max 2200000pF~4700000pF : 10.0% max 10000000pF : 22.5% max Insulation Resistance: 1200pF~22000pF (ItemΔJ) : 500MΩ min 100000pF : 250MΩ min 1000000pF : 12.5MΩ min 2200000pF : 5MΩ min 4700000pF~10000000pF : 2.5MΩ min Rated Voltage:25VDC B Capacitance change : 10000pF : Within ±12.5% 10000000pF : Within ±22.5% tanδ: 10000pF : 5.0% max 10000000pF : 22.5% max Insulation Resistance: 10000pF : 500MΩ min 10000000pF : 2.5MΩ min Rated Voltage:35VDC B Capacitance change : 2200000pF : Within ±15.0% 4700000pF : Within ±22.5% tanδ: 2200000pF~4700000pF : 10.0% max Insulation Resistance: 2200000pF : 5MΩ min 4700000pF : 2.5MΩ min Rated Voltage:50VDC B Capacitance change : 100pF~39000pF : Within ±12.5% 47000pF~1000000pF : Within ±15.0% tanδ: 100pF~39000pF : 5.0% max 47000pF~1000000pF : 7.5% max Insulation Resistance: 100pF~39000pF : 500MΩ min 47000pF~100000pF : 250MΩ min 220000pF : 125MΩ min 470000pF : 25MΩ min 1000000pF : 12.5MΩ min	Rated Voltage:10VDC F Capacitance change: Within ±30.0% tanδ: 4700000pF~10000000pF : 20.0% max Insulation Resistance: 4700000pF : 5MΩ min 10000000pF : 2.5MΩ min Rated Voltage:16VDC F Capacitance change: Within ±30.0% tanδ: 100000pF : 15.0% max 2200000pF : 17.5% max Insulation Resistance: 100000pF : 250MΩ min 2200000pF : 12.5MΩ min Rated Voltage:25VDC F Capacitance change: Within ±30.0% tanδ: 10000pF~47000pF (ItemΔJ) : 12.5% max Insulation Resistance: 10000pF~47000pF (ItemΔJ) : 250MΩ min Rated Voltage:35VDC F Capacitance change: Within ±30.0% tanδ: 10000000pF : 20.0% max Insulation Resistance: 10000000pF : 25MΩ min Rated Voltage:50VDC F Capacitance change : 10000pF~1000000pF : Within ±30.0% tanδ: 10000pF~100000pF : 12.5% max 220000pF~470000pF : 15.0% max 1000000pF : 17.5% max Insulation Resistance: 10000pF~100000pF : 250MΩ min 220000pF~470000pF : 125MΩ min 1000000pF : 25MΩ min	

Withstanding voltage is also referred to as "voltage proof" under IEC specifications.

AXIAL LEADED CERAMIC CAPACITORS

Item	Specified Value			Test Methods and Remarks
	Temterature Compensating (Class1)	High Permittivity (Class2)		
	Multilayer type	Multilayer type (Characteristics:B)	Multilayer type (Characteristics:F)	
19. High Temperature Lading Test	Appearance : No significant abnormality Withstanding Voltage : No abnormality	Appearance : No significant abnormality Withstanding Voltage : No abnormality	Appearance : No significant abnormality Withstanding Voltage : No abnormality	Temperature: $85 \pm \begin{smallmatrix} 3 \\ 0 \end{smallmatrix}^{\circ}\text{C}$ Duration: $1000 \pm \begin{smallmatrix} 48 \\ 0 \end{smallmatrix}$ hrs Applied voltage: Rated voltage×2 (Class 1) (Class 2) Rated voltage×1.5 (Class 2: B 220000pF~10000000pF) Preconditioning: 1 hr of preconditioning at $150 \begin{smallmatrix} +10 \\ -10 \end{smallmatrix}^{\circ}\text{C}$ followed by 48±4 hrs of recovery under the standard condition. Recovery: 24±2hrs of recovery under the standard condition after the removal from test cham- ber. (Class1) : 1 hr of preconditioning at $150 \begin{smallmatrix} +10 \\ -0 \end{smallmatrix}^{\circ}\text{C}$ fol- lowed by 48±4 hrs of recovery under the standard condition after the removal from chamber. (Class 2)
	Capacitance change : 8.2pF or under :Within ±0.3pF 10pF or over :Within ±3.0% Q: :8.2pF or under :10pF 30pF 33pF or over: Q≥200+10C Q≥275+2.5C Q≥350	Rated Voltage:16VDC B Capacitance change : 1200pF~22000pF (Item△J) : Within ±12.5% 100000pF : Within ±15.0% 1000000pF~2200000pF : Within ±15.0% 4700000pF~10000000pF : Within ±22.5% tanδ: 1200pF~22000pF (Item△J) : 5.0% max 100000pF : 7.5% max 1000000pF : 7.5% max 2200000pF~4700000pF : 10.0% max 10000000pF : 22.5% max Insulation Resistance: 1200pF~22000pF (Item△J) : 1000MΩ min 100000pF : 500MΩ min 1000000pF : 50MΩ min 2200000pF : 25MΩ min 4700000pF~10000000pF : 5MΩ min	Rated Voltage:10VDC F Capacitance change : Within ±30.0% tanδ: 4700000pF~10000000pF :20.0% max Insulation Resistance: 4700000pF :10MΩ min 10000000pF :5MΩ min	
	Insulation resistance: 1000MΩ min.	Insulation Resistance: 1000000pF : 1000MΩ min 10000000pF : 500MΩ min 10000000pF : 50MΩ min 22000000pF : 25MΩ min 47000000pF : 5MΩ min	Insulation Resistance: 22000000pF :17.5% max 100000pF : 500MΩ min 2200000pF :25MΩ min	
	C:Nominal Capacitance [pF]		Rated Voltage:25VDC F Capacitance change : Within ±30.0% tanδ: 10000pF~47000pF (Item△J) : 10.0% max Insulation Resistance: 10000pF~47000pF (Item△J) : 500MΩmin	
		Rated Voltage:25VDC B Capacitance change : 10000pF : Within ±12.5% 10000000pF : Within ±22.5% tanδ: 10000pF : 5.0% max 10000000pF : 22.5% max Insulation Resistance: 10000pF : 1000MΩ min 10000000pF : 5MΩ min	Rated Voltage:35VDC F Capacitance change : Within ±30.0% tanδ: 10000000pF :20.0% max Insulation Resistance: 10000000pF :5MΩ min	
		Rated Voltage:35VDC B Capacitance change : 22000000pF : Within ±15.0% 47000000pF : Within ±22.5% tanδ: 22000000pF~47000000pF : 10.0% max Insulation Resistance: 22000000pF : 25MΩ min 47000000pF : 5MΩ min	Rated Voltage:50VDC F Capacitance change : 10000pF~10000000pF :Within ±30.0% tanδ: 10000pF~1000000pF :10.0% max 2200000pF~4700000pF :12.5% max 10000000pF :17.5% max Insulation Resistance: 10000pF~1000000pF :500MΩ min 220000pF~470000pF :250MΩ min 1000000pF :50MΩ min	
		Rated Voltage:50VDC B Capacitance change : 100pF~39000pF : Within ±12.5% 47000pF~1000000pF : Within ±15.0% tanδ: 100pF~39000pF : 5.0% max 47000pF~1000000pF : 7.5% max Insulation Resistance: 100pF~39000pF :1000MΩ min 47000pF~1000000pF :500MΩ min 220000pF :250MΩ min 470000pF :100MΩ min 1000000pF :50MΩ min		

Note on standard condition: "standard condition" referred to herein is defined as follows:

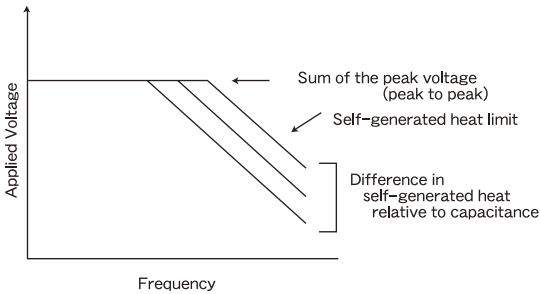
5 to 35°C of temperature, 45 to 85% relative humidity, and 86 to 106kPa of air pressure.

When there are questions concerning measurement results:

In order to provide correlation data, the test shall be conducted under condition of $20 \pm 2^{\circ}\text{C}$ of temperature, 60 to 70% relative humidity, and 86 to 106kPa of air pressure. Unless otherwise specified, all the tests are conducted under the "standard condition."

Withstanding voltage is also referred to as "voltage proof" under IEC specifications.

Precautions on the use of Axial Leaded Ceramic Capacitors

Stages	Precautions	Technical considerations
1. Circuit Design	◆ Verification of operating environment, electrical rating and performance 1. A malfunction in medical equipment, spacecraft, nuclear reactors, etc. may cause serious harm to human life or have severe social ramifications. As such, any capacitors to be used in such equipment may require higher safety and/or reliability considerations and should be clearly differentiated from components used in general purpose applications. ◆ Verification of Rated voltage (DC rated voltage) 1. The operating voltage for capacitors must always be lower than their rated values. If an AC voltage is loaded on a DC voltage, the sum of the two peak voltages should be lower than the rated value of the capacitor chosen. For a circuit where both an AC and a pulse voltage may be present, the sum of their peak voltages should also be lower than the capacitor's rated voltage. 2. Even if the applied voltage is lower than the rated value, the reliability of capacitors might be reduced if either a high frequency AC voltage or a pulse voltage having rapid rise time is present in the circuit. ◆ Self-generated heat (Verification of Temperature) 1. If the capacitors specified only for DC use are used in AC or pulse circuits, the AC or a pulse current can generate heat inside the capacitor so the self-generated temperature rise should be limited to within 20°C. The surface temperature measured should include this self-temperature rise. Therefore, it is required to limit capacitor surface temperature including self-generated heat should not exceed the maximum operating temperature of +85°C. ◆ Operating Environment precautions 1. Capacitors should not be used in the following environments: (1) Environmental conditions to avoid - exposure to water or salt water. - exposure to moisture or condensation. - exposure to corrosive gases (such as hydrogen sulfide, sulfurous acid, chlorine, and ammonia)	1-1. When an AC or a pulse voltage is applied to capacitors specified for DC use, even if the voltage is less than the rated voltage, the AC current or pulse current running through the capacitor will cause the capacitor to self-generate heat because of the loss characteristics. The amount of heat generated depends on the dielectric materials used, capacitance, applied voltage, frequency, voltage waveform, etc. The surface temperature changes due to emitted heat which differs by capacitor shape or mounting method. Please contact Taiyo Yuden with any questions regarding emitted heat levels in your particular application. It is recommended the temperature rise be measured in the actual circuit to be used. 1-2. For capacitors, the voltage and frequency relationship is generally determined by peak voltage at low frequencies, and by self-generated heat at high frequencies. (Refer to the following curve.) 
2. PCB Design	1. When capacitors are mounted onto a PC board, hole dimensions on the board should match the lead pitch of the component, if not it will cause breakage of the terminals or cracking of terminal roots covered with resin as excess stress travels through the terminal legs. As a result, humidity resistance performance would be lost and may lead to a reduction in insulation resistance and cause a withstand voltage failure.	
3. Considerations for automatic insertion	◆ Adjustment Automatic Insertion machines (leaded components) 1. When inserting capacitors in a PC board by auto-insertion machines the impact load imposed on the capacitors should be minimized to prevent the leads from chucking or clinching.	1. When installing products, care should be taken not to apply distortion stress as it may deform the products. 2. Our company recommends the method to place the lead with fewer loads that join the product.

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4. Soldering	◆ Selection of Flux - When soldering capacitors on the board, flux should be applied thinly and evenly. - Flux used should be with less than or equal to 0.1 wt% (equivalent to Choline) of halogenated content. Flux having a strong acidity content should not be applied. - When using water-soluble flux, special care should be taken to properly clean the boards. ◆ Wave Soldering - Temperature, time, amount of solder, etc. are specified in accordance with the following recommended conditions. - Do not immerse the entire capacitor in the flux during the soldering operation. Only solder the lead wires on the bottom of the board. ◆ Recommended conditions for using a soldering iron: Put the soldering iron on the land-pattern. Soldering iron's temperature - below 350°C Duration - 3 seconds or less Numbers of times - 1 times The soldering iron should not directly touch the capacitor.	- Flux is used to increase solderability in wave soldering, but if too much is applied, a large amount of flux gas may be emitted and may detrimentally affect solderability. To minimize the amount of flux applied, it is recommended to use a flux-bubbling system. - With too much halogenated substance (Chlorine, etc.) content is used to activate the flux, an excessive amount of residue after soldering may lead to corrosion of the terminal electrodes or degradation of insulation resistance on the surface of the capacitors. - Since the residue of water-soluble flux is easily dissolved by water content in the air, the residue on the surface of capacitors in high humidity conditions may cause a degradation of insulation resistance and therefore affect the reliability of the components. The cleaning methods and the capability of the machines used should also be considered carefully when selecting water-soluble flux. - If capacitors are used beyond the range of the recommended conditions, heat stresses may cause cracks inside the capacitors, and consequently degrade the reliability of the capacitors. - When the capacitors are dipped in solder, some soldered parts of the capacitor may melt due to solder heat and cause short-circuits or cracking of the ceramic material. Deterioration of the resin coating may lower insulation resistance and cause a reduction of withstand voltage. - If products are used beyond the range of the recommended conditions, heat stress may deform the products, and consequently degrade the reliability of the products.
5. Cleaning	◆ Board cleaning When cleaning the mounted PC boards, make sure that cleaning conditions are consistent with prescribed usage conditions.	The resin material used for the outer coating of capacitors is occasionally a wax substance for moisture resistance which can easily be dissolved by some solutions. So before cleaning, special care should be taken to test the component's vulnerability to the solutions used. When using water-soluble flux please clean the PCB with purified water sufficiently and dry thoroughly at the end of the process. Insufficient washing or drying could lower the reliability of the capacitors.
6. Post-cleaning-process	◆ Application of resin molding, etc. to the PCB and components. Please contact your local Taiyo Yuden sales office before performing resin coating or molding on mounted capacitors. Please verify on the actual application that the coating process will not adversely affect the component quality.	1-1. The thermal expansion and coefficient of contraction of the molded resin are not necessarily matched with those of the capacitor. The capacitors may be exposed to stresses due to thermal expansion and contraction during and after hardening. This may lower the specified characteristics and insulation resistance or cause reduced withstand voltage by cracking the ceramic or separating the coated resin from the ceramics. 1-2. With some types of mold resins, the resin's decomposition gas or reaction gas may remain inside the resin during the hardening period or while left under normal conditions, causing a deterioration of the capacitor's performance. 1-3. Some mold resins may have poor moisture proofing properties. Please verify the contents of the resins before they are applied. 1-4. Please contact Taiyo Yuden before using if the hardening process temperature of the mold resins is higher than the operating temperature of the capacitors.
7. Handling	◆ Mechanical considerations - Be careful not to subject the capacitors to excessive mechanical shocks. Withstanding voltage failure may result. - If ceramic capacitors are dropped onto the floor or a hard surface they should not be used.	- Because the capacitor is made of ceramic, mechanical shocks applied to the board may damage or crack the capacitors. - Ceramic capacitors which are dropped onto the floor or a hard surface may develop defects and have a higher risk of failure over time.
8. Storage conditions	◆ Storage - To maintain the solderability of terminal electrodes and to keep the packaging material in good condition, care must be taken to control temperature and humidity in the storage area. Humidity should especially be kept as low as possible. Recommended conditions: Ambient temperature Below 40 °C Humidity Below 70% RH. Products should be used within 6 months after delivery. After the above period, the solderability should be checked before using the capacitors. - Capacitors should not be kept in an environment filled with decomposition gases such as (sulfurous hydrogen, sulfurous acid, chlorine, ammonia, etc.) - Capacitors should not be kept in a location where they may be exposed to moisture, condensation or direct sunlight.	Under high temperature/high humidity conditions, the decrease in solderability due to the oxidation of terminal electrodes and deterioration of taping and packaging characteristics may be accelerated.